AMENDMENTS TO THE CLAIMS

This listing of claims will replace all prior versions, and listings, of claims in the application:

Listing of Claims:

Claim 1 (currently amended): A light transmitting substrate with a transparent conductive film, comprising[:]

a light transmitting substrate[;] and

a continuous transparent conductive film having a thickness of 12 to 2 nm formed on the light transmitting substrate.

Claim 2 (original): The light transmitting substrate with a transparent conductive film according to claim 1, wherein the transparent conductive film is made of an aggregate of columnar single crystals.

Claim 3 (original): The light transmitting substrate with a transparent conductive film according to claim 1 or 2, wherein the transparent conductive film has a maximum surface roughness within a range from 1 to 20 nm.

Claim 4 (currently amended): The light transmitting substrate with a transparent conductive film according to any one of claims 1 to 3 claim 1 or 2, wherein the transparent conductive film has an average surface roughness within a range from 0.1 to 10 nm.

Claim 5 (currently amended): The light transmitting substrate with a transparent conductive film according to any one of claims 1 to 4claim 1 or 2, wherein the transparent conductive film is a thin film made of a tin-doped indium oxide.

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Claim 6 (original): The light transmitting substrate with a transparent conductive film according to claim 5, wherein tin atoms are uniformly distributed in the thin film made of the tindoped indium oxide.

Claim 7 (currently amended): The light transmitting substrate with a transparent conductive film according to any one of claims 1 to 6 claim 1 or 2, wherein the transparent conductive film is a conductive film formed on the substrate through a spray pyrolysis deposition method or a pyrosol method.

Claim 8 (original): The light transmitting substrate with a transparent conductive film according to claim 7, wherein the conductive film is formed at a temperature on the substrate within a range from 400 to 750°C.

Claim 9 (currently amended): The light transmitting substrate with a transparent conductive film according to any one of claims 1 to 8claim 1 or 2, wherein a transmittance to light having a wavelength of 400 nm is 88% or more.

Claim 10 (currently amended): The light transmitting substrate with a transparent conductive film according to any one of (1) to (9) claim 1 or 2, wherein a transmittance to light having a wavelength of 350 nm is 85% or more.

Claim 11 (currently amended): The light transmitting substrate with a transparent conductive film according to any one of claims 1 to 10 claim 1 or 2, wherein a whole light transmittance is 90% or more.

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